

## Ab initio thermoelectric properties

Bin Xu<sup>1</sup>, Momar Diakhate<sup>1</sup>, Alessio Filippetti<sup>2</sup>,  
Matthieu Verstraete<sup>1</sup>

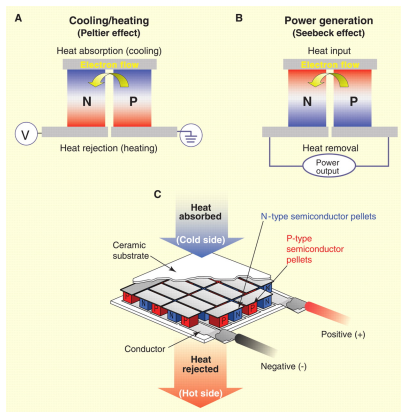
<sup>1</sup> Department of Physics, University of Liège, Belgium

<sup>2</sup> CNR-IOM UOS Cagliari, Dipartimento di Fisica, Università di Cagliari, Italy

Nov 07, 2012

- 1 Introduction
- 2 Theory
- 3 Results
- 4 Conclusions & Discussion

# Thermoelectric effect



*L.E. Bell, Science 321, 1457 (2008)*

- Seebeck effect:  $\mathbf{E} = \mathbf{S}\nabla T$
- Peltier effect:  $\dot{Q}_P = \Pi I = STI$

# Advantages

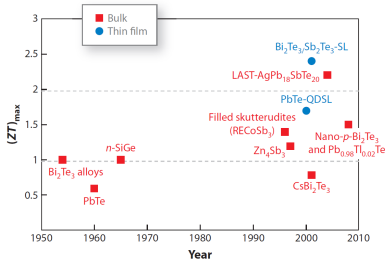
- Solid state
  - durable
  - small size
  - no moving parts
  - quiet
  - alternative to fossil fuels
  - no greenhouse gas emission
- Power generation
  - waste heat harvesting
  - conditions where no other energy sources are suitable (Radioisotope Thermoelectric Generator, RTG)
- Cooling/Heating
  - reversibility (to cool or heat with the same module)
  - spot cooling/heating



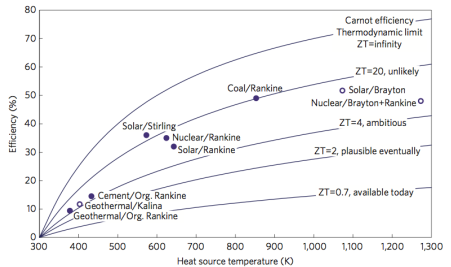
# Disadvantages

- Cost
- Efficiency

Figure of merit:  $ZT = \frac{\sigma S^2 T}{\kappa_l + \kappa_e}$



T.M. Tritt, *Annu. Rev. Mater. Res.* **41**, 433 (2011)



C.B. Vining, *Nature Materials* **8**, 83 (2009)

# To maximize ZT

$$ZT = \frac{\sigma S^2 T}{\kappa_l + \kappa_e}$$

- Phonon Glass-Electron Crystal
  - Minimize lattice thermal conductivity  $\kappa_l$
  - Maximize power factor  $\sigma S^2$

*G.A. Slack, CRC Handbook of Thermoelectrics, ed. by D.M. Rowe, CRC Press, Boca Raton, FL, 1995, p. 407.*

# Trade-off among the transport coefficients

- $\sigma$  v.s.  $S$

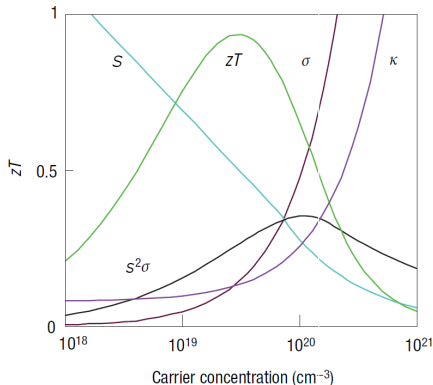
Mott relation

$$S_d = \frac{\pi^2}{3} \frac{k_B}{q} k_B T \left\{ \frac{1}{\sigma} \frac{d\sigma(E)}{dE} \right\}_{E=\epsilon_F}$$

- $\sigma$  v.s.  $\kappa_e$

Wiedemann-Franz law

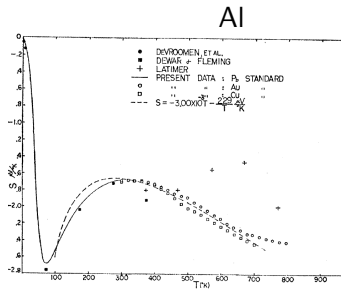
$$\kappa_e = L_0 \sigma T$$



*G.J. Snyder and E.S. Toberer, Nature Materials 7, 105-114 (2008)*

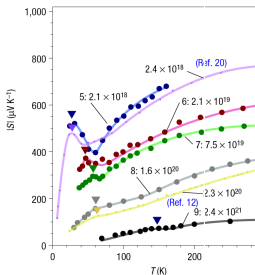
# Phonon-drag effect

- $S_g \sim \frac{C_v}{Ne} \alpha = \frac{C_v}{Ne} \frac{P_{el-ph}}{P_{el-ph} + P_{ph-ph} + P_{ph-else}}$
- When el-ph interaction is strong
- Important at low temperatures



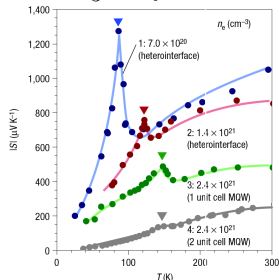
R. Griphover et al., Phys. Rev. (1967)

## doped SrTiO<sub>3</sub>



Ohta et al., Nat. Mater. (2007)

## SrTiO<sub>3</sub> MQW



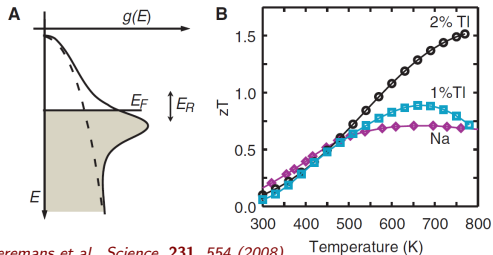


$$\kappa_l = \frac{1}{3} v c_v l$$

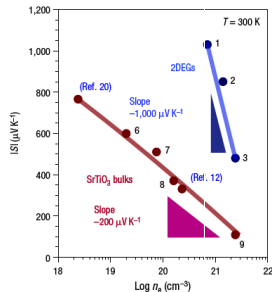
- Mass fluctuation (ternary/quaternary compounds)
- Rattling (clathrates, skutterudites)
- Grain boundary (nano composites)
- Interface (thin films, multilayer systems)
- The minimum  $\kappa_l$  is limited, when the phonon mean free path becomes close to the interatomic distance.

# Enhancing the power factor $\sigma S^2$

- Doping in semiconductors:  $\sigma \nearrow$
- Mott relation:  $S = \frac{\pi^2}{3} \frac{k_B}{q} k_B T \left\{ \frac{1}{n} \frac{dn(E)}{dE} + \frac{1}{\mu} \frac{d\mu(E)}{dE} \right\}_{E=\epsilon_F}$
- DOS engineering
  - resonant scattering (TI impurity levels in PbTe)
- Low dimensionality (quantum confinement)
  - 0D: quantum dots
  - 1D: nanowires
  - 2D: quantum wells and superlattices



J.P. Heremans et al., *Science*, **231**, 554 (2008)



Ohta et al., *Nat. Mater.* (2007)

- 1 Introduction
- 2 Theory**
- 3 Results
- 4 Conclusions & Discussion

# Theoretical predictions

- Phonon-phonon interactions
  - lattice thermal conductivity
- Electron-phonon interactions
  - Electrical conductivity
  - Seebeck coefficient
  - Electronic thermal conductivity
- Coupled term
  - Phonon drag Seebeck
- Other interactions
  - Impurity scattering with electrons and phonons
  - Defects, grain boundaries

- Boltzmann's transport equation (BTE without magnetic field)

$$-\mathbf{v}_{\mathbf{k}} \cdot \frac{\partial f_{\mathbf{k}}}{\partial T} \nabla T - \mathbf{v}_{\mathbf{k}} \cdot e \frac{\partial f_{\mathbf{k}}}{\partial \epsilon_{\mathbf{k}}} \mathbf{E} = - \left. \frac{\partial f_{\mathbf{k}}}{\partial t} \right|_{scatt}$$

- Standard solution with relaxation time approximation

$$- \left. \frac{\partial f_{\mathbf{k}}}{\partial t} \right|_{scatt} = \frac{f_{\mathbf{k}} - f_{\mathbf{k}}^0}{\tau_{\mathbf{k}}}$$

- Variational method

$$f_{\mathbf{k}} \equiv f_{\mathbf{k}}^0 - \phi_{\mathbf{k}} \frac{\partial f_{\mathbf{k}}^0}{\partial \epsilon_{\mathbf{k}}}$$
$$- \left. \frac{\partial f_{\mathbf{k}}}{\partial t} \right|_{scatt} = \sum_{\mathbf{k}'} Q_{\mathbf{k}\mathbf{k}'} \phi_{\mathbf{k}'}$$

# Constant relaxation time approximation

- Advantage: simple calculation (band structure)
- Disadvantage:
  - unknown constant relaxation time
  - system with anisotropic scattering

$$\sigma_{\alpha\beta}(\epsilon) = e^2 \sum_{\mathbf{k}} \tau_{\mathbf{k}} v_{\alpha}(\mathbf{k}) v_{\beta}(\mathbf{k}) \delta(\epsilon - \epsilon_{\mathbf{k}})$$

$$\rightarrow e^2 \tau \sum_{\mathbf{k}} v_{\alpha}(\mathbf{k}) v_{\beta}(\mathbf{k}) \delta(\epsilon - \epsilon_{\mathbf{k}})$$

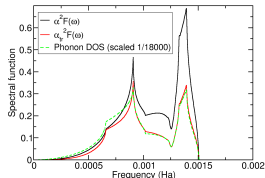
$$\sigma_{\alpha\beta} = \frac{1}{V_{cell}} \int \sigma_{\alpha\beta}(\epsilon) \left( -\frac{\partial f}{\partial \epsilon} \right) d\epsilon$$

$$S_{\alpha\beta} = \frac{1}{eT} \frac{\int \sigma_{\alpha\beta}(\epsilon) (\epsilon - \mu) \left( -\frac{\partial f}{\partial \epsilon} \right) d\epsilon}{\int \sigma_{\alpha\beta}(\epsilon) \left( -\frac{\partial f}{\partial \epsilon} \right) d\epsilon}$$

# Variational solution to the BTE<sup>†</sup>

- Scattering operator

$$Q_{\alpha n, \beta n'} = \frac{2\pi V_{\text{cell}} N(\epsilon_F)}{\hbar k_B T} \int d\epsilon \int d\epsilon' \int d\omega \alpha_{tr}^2 F(\omega) J(n, n', \epsilon, \epsilon') f(\epsilon) [1 - f(\epsilon')] \times \{ [N(\omega) + 1] \delta(\epsilon - \epsilon' - \hbar\omega) + N(\omega) \delta(\epsilon - \epsilon' + \hbar\omega) \}$$



- Transport spectral function

$$\alpha_{tr}^2(s, s', \alpha, \beta, \epsilon, \epsilon') F(\omega) = \frac{1}{2N(\epsilon_F)} \sum_{\mathbf{k}\mathbf{k}'} |g_{\mathbf{k}\mathbf{k}'}|^2 [F_\alpha(\mathbf{k}) - sF_\alpha(\mathbf{k}')] \times [F_\beta(\mathbf{k}) - s'F_\beta(\mathbf{k}')] \delta(\epsilon_{\mathbf{k}} - \epsilon) \delta(\epsilon_{\mathbf{k}'} - \epsilon') \delta(\omega_{\mathbf{q}} - \omega)$$

<sup>†</sup> P. B. Allen, *Phys. Rev. B* **17**, 3725 (1978)

# LOVA (lowest-order variational approximation) and beyond

- Transport coefficients

$$\rho_{\alpha\beta} = \left(\frac{m}{n}\right)_{\text{eff}} \frac{1}{e^2} \frac{1}{\tau_{\alpha\beta}} = \frac{1}{2e^2(Q^{-1})_{\alpha 0, \beta 0}} \approx \frac{1}{2e^2} Q_{\alpha 0, \beta 0}$$

$$S_{\alpha\beta} = -\frac{\pi k_B (Q^{-1})_{\alpha 0, \beta 1}}{\sqrt{3}e (Q^{-1})_{\alpha 0, \beta 0}} \approx \frac{\pi k_B}{\sqrt{3}e} Q_{\alpha 0, \beta 1} / Q_{\alpha 1, \beta 1}$$

- Elastic LOVA

- $\epsilon = \epsilon' = \epsilon_F$
- valid when  $\alpha_{tr}^2 F$  depends weakly on  $\epsilon$  and  $\epsilon'$
- Seebeck coefficient vanishes! (el-hole symmetric)

$$\frac{1}{\tau_{\alpha\beta}} = \frac{4\pi k_B T}{\hbar} \int_0^\infty \frac{d\omega}{\omega} \frac{x^2}{\sinh^2 x} \alpha_{tr}^2 F(\omega) \text{ where } x = \omega/2k_B T$$

- Beyond LOVA

- with higher-order terms of  $Q_{\alpha n, \beta n'}$
- including Fermi smearing

$$\frac{1}{\tau_{\alpha\beta}} = N(\epsilon_F) v_\alpha(\epsilon_F) v_\beta(\epsilon_F) Q_{\alpha 0, \beta 0}$$



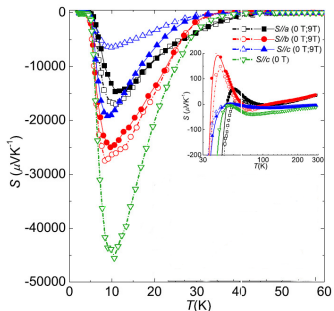
- 1 Introduction
- 2 Theory
- 3 Results**
- 4 Conclusions & Discussion

Constant  $\tau$

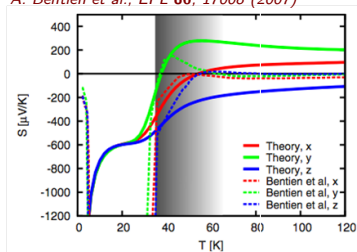
# FeSb<sub>2</sub>: Colossal Seebeck coefficient at low T

- Experiment
  - Record low-T thermopower
  - $S_{max} \approx -45000 \mu\text{VK}^{-1}$  at  $T \approx 10$  K
- Theory (J.M. Tomczak *et al.*)
  - Kubo approach
  - Agreement only at intermediate temperatures
- Theory (M. Diakhate *et al.*)
  - Boltzmann approach
  - Constant relaxation time

*M. Diakhate et al., Phys. Rev. B* **84**, 125210 (2011)

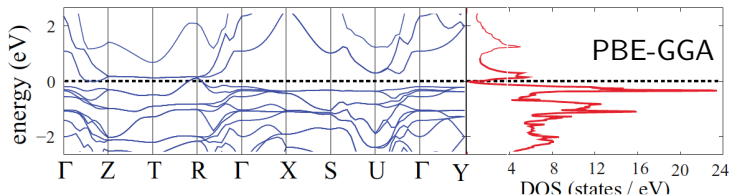


*A. Benti et al., EPL* **80**, 17008 (2007)

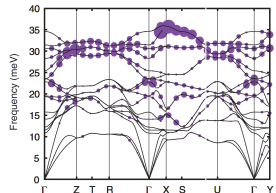
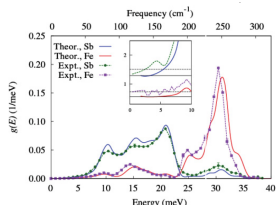


*J.M. Tomczak et al., Phys. Rev. B* **82**, 085104 (2010)

# FeSb<sub>2</sub>: electron, phonon and el-ph coupling

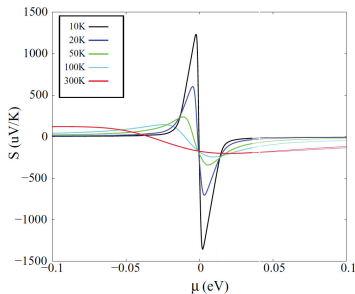
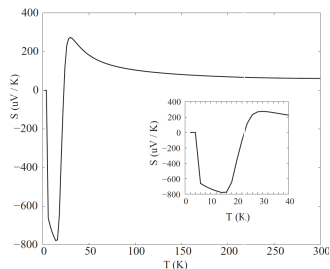


- Electronic band structure
  - $E_g = 37$  meV experimentally
  - semimetal from DFT
- Phonon DOS
  - Agree with expt.
  - Low-freq. Sb modes
  - High-freq. Fe modes
- Phonon linewidths due to EPC
  - Significant around Z, X, S
  - Future expt. needed



# FeSb<sub>2</sub>: Seebeck coefficient

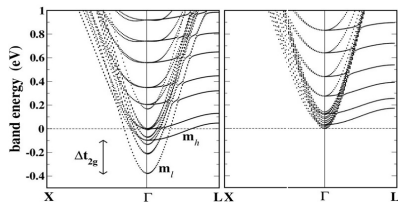
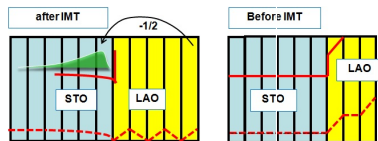
- $S_{max} \approx -800 \mu\text{V/K}^{-1}$  at  $T \approx 15$  K
- Phonon drag?  
 $\lambda = 0.24$  is weak
- $S$  becomes positive above  $T \approx 25$  K
- To maximize thermopower
  - Donor doping
  - $n = 3.2 \times 10^{15} \text{ cm}^{-3}$



Model  $\tau(\epsilon, T)$

# STO/LAO interface

- 2DEL at the interface
  - Tightly confined
- Polar catastrophe with  $> 4$  LAO layers
- $t_{2g}$  bands between bulk STO and STO/LAO
  - band effective mass
  - on-site band offset
  - inter-site band offset



pSIC-LDA

# Relaxation time model

- For elastic scattering
- For parabolic band

$$\tau(\epsilon, T) = F(T) \left( \frac{\epsilon - \epsilon_0}{k_B T} \right)^\lambda$$

$$F(T) = \tau_0 \left[ \left( \frac{T_0}{T} \right)^{-\gamma} + \left( \frac{\tau_0}{\tau_{\text{res}}} \right) \left( \frac{T_0}{T} \right)^\lambda \right]^{-1}$$

$$\lambda = \gamma = 3/2, \tau_0 = 3 \text{ fs}, T_0 = 20 \text{ K}$$

$$\tau_0/\tau_{\text{res}} = 0 \text{ for bulk STO}$$

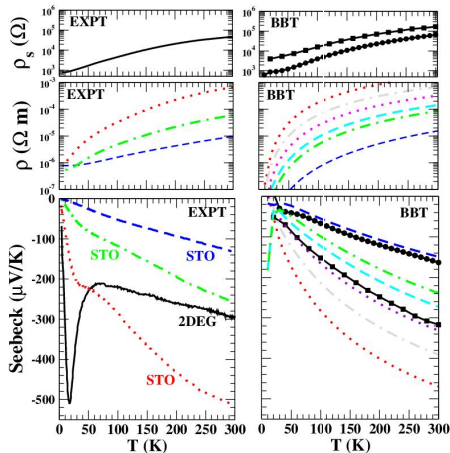
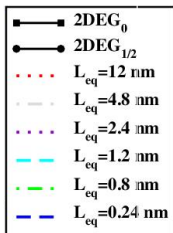
$$\tau_0/\tau_{\text{res}} = 40 \text{ for STO/LAO}$$

*K. Durczewski and M. Ausloos, Phys. Rev. B* **61**, 5303 (2000)



# Is Seebeck enhanced?

- Nb-doped bulk STO
  - agreement btwn theo. and expt.
  - $L_{eq} \searrow \rightarrow S \searrow$
  - confined 2DEG reduces  $S$
- STO/LAO interface
  - $S$  not improved over the bulk
  - phonon drag peak at 20 K?



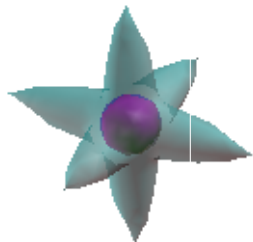
- Bulk STO:  
 $t_{2g}$  effective masses are anisotropic

$$m_{xy,j}^* = (0.7, 0.7, 8.8)$$

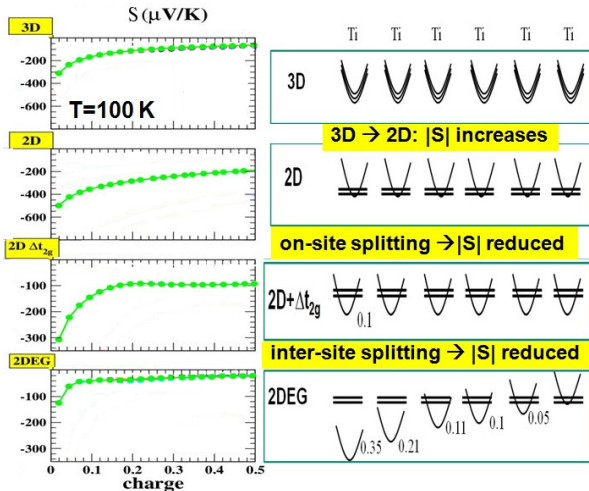
$$m_{xz,j}^* = (0.7, 8.8, 0.7)$$

$$m_{yz,j}^* = (8.8, 0.7, 0.7)$$

$$\epsilon_{v\alpha k} = \epsilon_{v\alpha}^0 + \frac{\hbar^2}{2} \left( \frac{k_x^2}{m_{\alpha x}} + \frac{k_y^2}{m_{\alpha y}} + \frac{k_z^2}{m_{\alpha z}} \right)$$



# Multiband model



Ab initio el-ph  $\tau$

- Elastic LOVA

- $\epsilon = \epsilon' = \epsilon_F$
- valid when  $\alpha_{tr}^2 F$  depends weakly on  $\epsilon$  and  $\epsilon'$
- Seebeck coefficient vanishes! (el-hole symmetric)

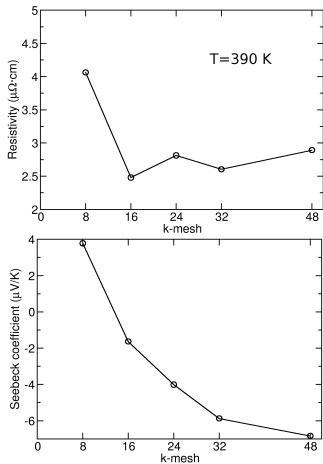
$$\frac{1}{\tau_{\alpha\beta}} = \frac{4\pi k_B T}{\hbar} \int_0^\infty \frac{d\omega}{\omega} \frac{x^2}{\sinh^2 x} \alpha_{tr}^2 F(\omega) \text{ where } x = \omega/2k_B T$$

- Beyond LOVA

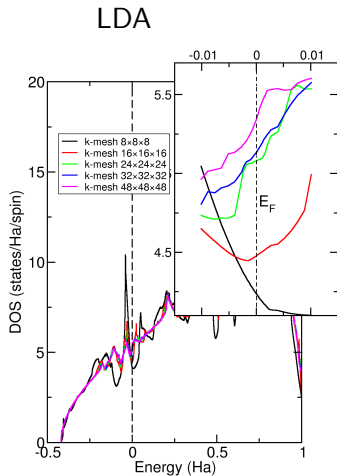
- with higher-order terms of  $Q_{\alpha n, \beta n'}$
- including Fermi smearing

$$\frac{1}{\tau_{\alpha\beta}} = N(\epsilon_F) v_\alpha(\epsilon_F) v_\beta(\epsilon_F) Q_{\alpha 0, \beta 0}$$

# Preliminary results of FCC aluminium



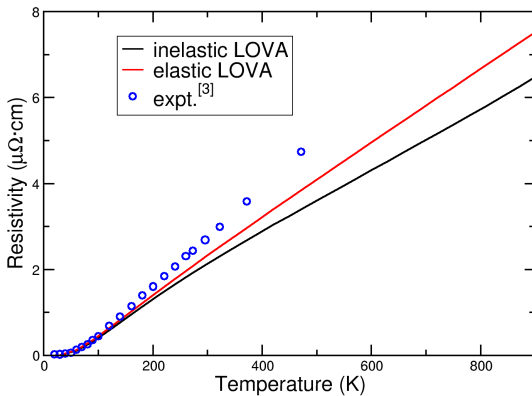
- Seebeck coefficient converges much slower than resistivity



- Seebeck coefficient is sensitive to the DOS around  $E_F$

# Electrical resistivity of Al

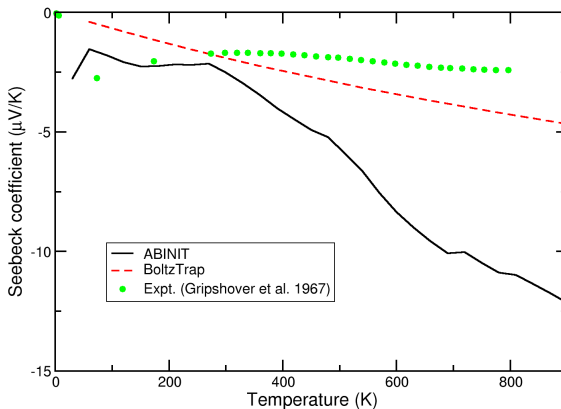
Both agree well with expt.



[Expt.] *Metals: Electronic Transport Phenomena*, edited by K.H. Hellwege et al., Group III, Vol. 15, Pt. a (1982)

# Seebeck coefficient of Al

- RTA result agrees better, with slightly larger T dependence
- Variational result overestimates at high T
- The curve is unsmooth



[Expt.] R. J. Griphover et al., *Phys. Rev. B* **163**, 598 (1967)



- 1 Introduction
- 2 Theory
- 3 Results
- 4 Conclusions & Discussion

# Conclusions & Discussion

- Constant/model relaxation time approach
  - less computationally demanding
  - reasonable result for  $S$
  - not parameter free
  - $\tau$  is difficult to estimate
  - anisotropy in  $\tau_{\mathbf{k}}$  is lost
  - to improve, fully *ab initio*  $\tau_{\mathbf{k}}$
- Variational approach
  - fully *ab initio*, where the EPC is considered explicitly
  - calculated  $\rho$  is robust for metals
  - computationally demanding
  - for large systems, difficult to converge
  - $Q$  may not be truncated at lowest order for insulators
  - to improve, efficient interpolation scheme is expected
  - to improve, new formulae for non-metals?

Momar Diakhate (FeSb<sub>2</sub>)  
Alessio Filippetti (STO/LAO)  
Bin Xu (Al)  
Matthieu Verstraete (All above)

# Discussion: RTA (relaxation time approximation)

- First-principles  $\tau_{\mathbf{k}}$  from EPC

$$\frac{1}{\tau_{\mathbf{k}}} = \frac{2\pi}{\hbar} \sum_{\mathbf{q}} |g_{\mathbf{k},\mathbf{k}+\mathbf{q}}|^2 \left\{ [f(\epsilon_{\mathbf{k}+\mathbf{q}}) + n_{\mathbf{q}}] \delta(\epsilon_{\mathbf{k}} - \epsilon_{\mathbf{k}+\mathbf{q}} + \hbar\omega_{\mathbf{q}}) + [1 + n_{\mathbf{q}} - f(\epsilon_{\mathbf{k}+\mathbf{q}})] \delta(\epsilon_{\mathbf{k}} - \epsilon_{\mathbf{k}+\mathbf{q}} - \hbar\omega_{\mathbf{q}}) \right\}$$

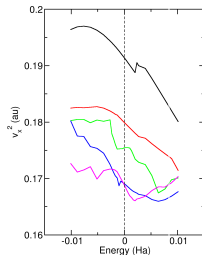
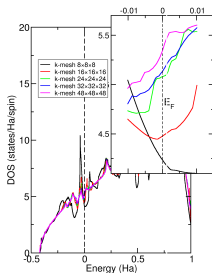
- Convergence

*G. Grimvall, The Electron-Phonon interaction in Metals, (North-Holland, Amsterdam, 1981)*

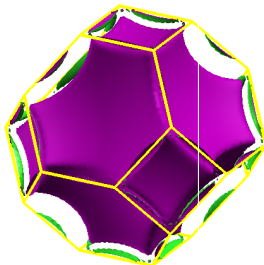
*O.D. Restrepo et al., Appl. Phys. Lett. 94, 212103 (2009)*

# Discussion: variational approach

- Metals
  - convergence of  $S$
  - better DOS and  $v_{\mathbf{k}}$  around  $\epsilon_F$
  - numerical-integration-caused uncertainty
- Intrinsic or lightly doped semiconductors/insulators
  - elastic LOVA does not work
  - new variational formulae?



- Interpolation scheme
  - Wannier functions (F. Giustino *et al.* Phys. Rev. B **76**, 165108 (2007) )
- Symmetry in DFPT GKK calculation
  - less direct calculations
  - need implementation
- $\mathbf{k}$  sampling for Fermi-surface integral
  - Fermi surface is usually complicated
  - Only include  $\mathbf{k}$  points near the Fermi surface?



Thank you!

Supplementary slides.



# Variational solution to the BTE<sup>†</sup>

- Scattering operator

$$Q_{\alpha n, \beta n'} = \frac{2\pi V_{cell} N(\epsilon_F)}{\hbar k_B T} \int d\epsilon \int d\epsilon' \int d\omega \\ \alpha_{tr}^2 F(\omega) J(n, n', \epsilon, \epsilon') f(\epsilon) [1 - f(\epsilon')] \\ \times \{ [N(\omega) + 1] \delta(\epsilon - \epsilon' - \hbar\omega) + N(\omega) \delta(\epsilon - \epsilon' + \hbar\omega) \}$$

- Transport coefficients

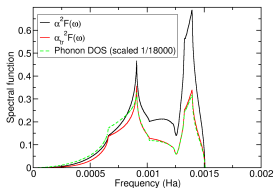
$$\rho_{\alpha\beta} = \frac{1}{2e^2 (Q^{-1})_{\alpha 0, \beta 0}} \approx \frac{1}{2e^2} Q_{\alpha 0, \beta 0}$$
$$S_{\alpha\beta} = -\frac{\pi k_B (Q^{-1})_{\alpha 0, \beta 1}}{\sqrt{3}e (Q^{-1})_{\alpha 0, \beta 0}} \approx \frac{\pi k_B}{\sqrt{3}e} Q_{\alpha 0, \beta 1} / Q_{\alpha 1, \beta 1}$$

- Generalized spectral functions

$$\alpha_{\text{tr}}^2(s, s', \alpha, \beta, \epsilon, \epsilon') F(\omega) = \frac{1}{2N(\epsilon_F)} \sum_{\mathbf{k}\mathbf{k}'} |g_{\mathbf{k}\mathbf{k}'}|^2 [F_\alpha(\mathbf{k}) - sF_\alpha(\mathbf{k}')] \times [F_\beta(\mathbf{k}) - s'F_\beta(\mathbf{k}')] \delta(\epsilon_{\mathbf{k}} - \epsilon) \delta(\epsilon_{\mathbf{k}'} - \epsilon') \delta(\omega_{\mathbf{q}} - \omega)$$

- Joint energy polynomials

$$J(s, s', n, n', \epsilon, \epsilon') = \frac{1}{4} [(n\epsilon) + s(n\epsilon')] [(n'\epsilon) + s'(n'\epsilon')]$$



$$F_\alpha(\mathbf{k}) = v_\alpha(\mathbf{k})/v_\alpha(\epsilon)$$

$$(n\epsilon) = \sigma_n(\epsilon)/N(\epsilon)v(\epsilon)$$

$$v_\alpha(\epsilon) = \left[ \frac{1}{N(\epsilon)} \sum_{\mathbf{k}} v_\alpha^2(\mathbf{k}) \delta(\epsilon_{\mathbf{k}} - \epsilon) \right]^{1/2}$$

$$\sigma_0 = 1, \sigma_1 = \sqrt{3}\epsilon/\pi k_B T$$